NSN 5961-01-010-7929



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-010-7929 **Inclosure Material:** Metal and plastic **Overall Length:** 0.688 inches **Overall Height:** 0.688 inches **Overall Diameter:** 0.375 inches **End Application:** 5821-00-295-5657 **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.164 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 55.0 collector to base voltage/static/emitter open and 33.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:**

Unc **Terminal Type And Quantity:** 2 ribbon and 1 threaded stud Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

NSN 5961-01-010-7929 Transistor - Page 2 of 2



Fiig:

A110a0